

DESCRIPTION

The A6345 is a low dropout (LDO) voltage regulator that can deliver up to 300mA of current while consuming only 3μ A of quiescent current (typical).

The input operating range is specified from 2.5V to 45V, making it an ideal choice for two to six or more primary cell battery-powered applications, 9V alkaline and one or two-cell Li-Ion-Power applications.

A6345 provides wide input voltage range and ensure the stability of fixed output voltage of 1.8V, 2.5, 3.0, 3.3V and 5.0V.

The A6345 is available in SOT-23, SOT-25 and SOT89-3 packages.

ORDERING INFORMATION

| Package Type | Part Number | | | |
|--------------------------------|-------------------------|---------------|--|--|
| SOT-23 | Γa | A6345E3R-XX | | |
| SPQ: 3,000pcs/Reel | E3 | A6345E3VR-XX | | |
| SOT-25 | E5 | A6345E5R-XX | | |
| SPQ: 3,000pcs/Reel | ED | A6345E5VR-XX | | |
| SOT89-3 | 142 | A6345K3R-XXZ | | |
| SPQ: 1,000pcs/Reel | K3 | A6345K3VR-XXZ | | |
| | XX: Output Voltage | | | |
| | 25=2.5V; 33=3.3V | | | |
| Note | Z: Package Type | | | |
| | see pin description | | | |
| | V: Halogen free Package | | | |
| | R: Tape & Reel | | | |
| AiT provides all RoHS products | | | | |

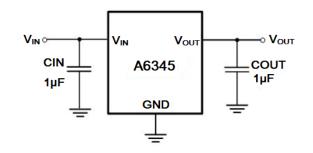
FEATURES

- Reduced Ground Current During Dropout
- Faster Startup Time
- 3.0µA Typical Quiescent Current
- Input Operating Voltage Range: 2.5V to 45V
- 300mA Output Current
- Low Dropout Voltage, 335mV Typical@100mA for 3.3Vout.
- ±2% Typical Output Voltage Tolerance, ±1% can be customized
- 1.8V, 2.5, 3.0, 3.3V, 5.0V Fixed Output Voltage
- Current Limit Protection
- Over Temperature Protection
- Available in SOT-23, SOT-25 and SOT89-3 packages

APPLICATION

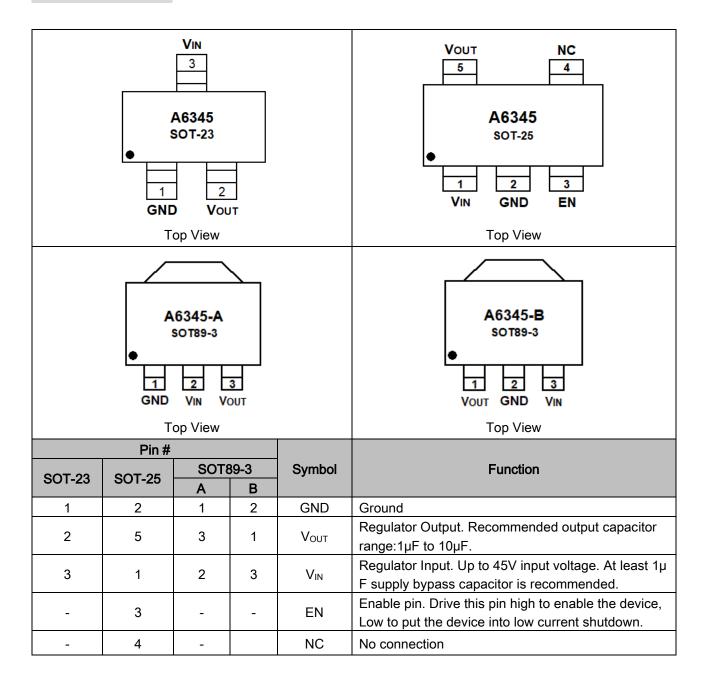
- Battery-Powered Devices
- Battery-Powered Alarm Circuits
- Smoke Detectors
- CO₂ Detectors
- Smart Battery Packs
- Low Quiescent Current Voltage Reference
- BMS systems
- Motor control system/Industrial control system
- Power Meter/Instrument
- Solar-Powered Instrument
- White Goods
- Vehicle-mounted system
- Automotive Head Unit
- Security Equipment
- Communication Equipment

TYPICAL APPLICATION





PIN DESCRIPTION





ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range, unless otherwise noted^{NOTE1}

| V _{IN} , Input Voltage | -0.3V ~ 50V | | | |
|--|---------------------------|--------|--|--|
| V _{EN} , Enable Input Voltage | -0.3V ~ V _{IN} | | | |
| T _J , Junction Temperature | -40°C ~ 150°C | | | |
| P _D , Continuous Power Dissipation ^{NOTE2} | Internally Limited | | | |
| ESD Ratings | | | | |
| V _(ESD) , Electrostatic Discharge | Human-body model (HBM) | ±4000V | | |
| | Charge device model (CDM) | ±1500V | | |

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Unit Parameter Symbol Min. Max. 2.5 45 V Input Supply Voltage VIN **Output Current** Ιουτ 0 300 mΑ 1 uF Capacitor of VIN pin CIN 10 Capacitor of VOUT Pin Соит 1 10 uF ESR 5 Equivalent series resistance 100 mΩ +85^{NOTE2} °C ΤA -40 **Operating Temperature**

over operating free-air temperature range, unless otherwise noted^{NOTE1}

NOTE1: All voltages are with respect to the GND pin.

NOTE2: The chip's operating temperature is determined by the junction temperature (T_J), the relationship between T_A and T_J , please refer to the application note as below.



ELECTRICAL CHARACTERISTICS

| $V_{IN} = V_{OUT} + 2V$, $C_{IN} = C_{OUT} = 1\mu$ F, $V_{OUT} = 3.3V$, typical values are at $T_A = +25^{\circ}$ C, unless otherwise noted. | | | | | | ted. | |
|--|--|---|------------------------|--------------|------|------|-------------------|
| Parameter | Symbol | Condit | ions | Min. | Тур. | Max. | Unit |
| Input Voltage | Vin | | | 2.5 NOTE3 | - | 45 | V |
| Output Voltage Accuracy | | I _{OUT} = 10mA | | -2.0 | - | 2.0 | % |
| Ground Pin Current | lq | No load | | - | 3.0 | 4.0 | μA |
| Shutdown Current | I _{Q-OFF} | V _{EN} =0V | | - | 0.1 | 1.0 | μA |
| Max Output CurrentNOTE4 | | | | 300 | 350 | - | mA |
| | | | Vout=1.8V | - | 450 | 550 | |
| | | | Vout=2.5V | - | 385 | 485 | |
| Dropout VoltageNOTE5 | V _{DROP} | I _{OUT} = 100mA | V _{OUT} =3.0V | 1 | 350 | 450 | mV |
| | | | Vout=3.3V | - | 335 | 435 | |
| | | | Vout=5.0V | - | 300 | 400 | |
| Line Regulation | ΔV _{OUT} | $V_{IN} = V_{OUT} + 2V$ | to 36V, | - | 0.05 | 0.2 | %/V |
| 5 | $\Delta V_{\text{IN}} \times V_{\text{OUT}}$ | I _{OUT} = 1mA | | | | | |
| Load Regulation | ΔV _{OUT} | $V_{IN} = V_{OUT} + 1V$, | | - | 5 | 20 | mV |
| | | IOUT = 1mA to 50mA | | | | | |
| Output Current Limit | I_LMT | V _{IN} =V _{OUT} +1V | | 300 | 450 | - | mA |
| Short Current | ISHORT | V _{OUT} = 0 | | - | 100 | - | mA |
| | PSRR | V _{OUT} = 3.3V, I _{OUT} = 10mA | f = 217Hz | - | 72 | - | - |
| Power Supply Rejection Ratio | | | f = 1kHz | - | 77 | - | dB |
| | | | f = 10KHz | - | 60 | - | |
| EN Input Threshold | V _{ENH} | | | 1.2 | - | - | v |
| | VENL | | | - | - | 0.4 | |
| Output Voltage Temperature Coefficient NOTE6 | ΔVουτ | $\frac{\Delta V_{OUT}}{\Delta T_{A} \times V_{OUT}} \begin{bmatrix} I_{LOAD} = 1mA \\ T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C \end{bmatrix}$ | | - | 100 | - | ppm/°C |
| Coefficient | $\Delta T_A \times V_{OUT}$ | | | | | | |
| Output Noise Voltage | en | V _{IN} =V _{OUT} +1V, I _{OUT} = 1mA , V _{OUT} =3.0V, f = 10Hz~100KHz | | - | 100 | - | µV _{RMS} |
| Thermal Shutdown Temperature | T _{SHDN} | | | - | 170 | - | °C |
| Thermal Shutdown Hysteresis | TSDH | | | - | 20 | - | °C |

NOTE3: $V_{IN} \ge V_{OUT (NOMINAL)}$, whichever is greater.

NOTE4: Maximum output current is affected by the PCB layout, size of metal trace, the thermal conduction path between metal layers, ambient temperature and the other environment factors of system. Attention should be paid to the dropout voltage when $V_{IN} < V_{OUT} + V_{DROP}$.

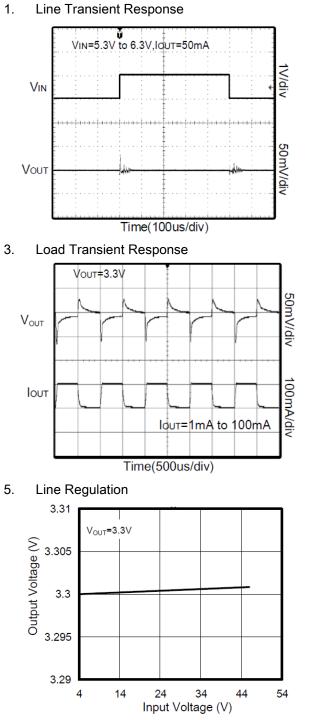
NOTE5: The dropout voltage is defined as V_{IN} - V_{OUT} , when V_{OUT} is 100mV below the value of V_{OUT} for V_{IN} = $V_{OUT (NOMINAL)}$ + 2V.

NOTE6: Output voltage temperature coefficient is defined as the worst-case voltage change divided by the total temperature range.

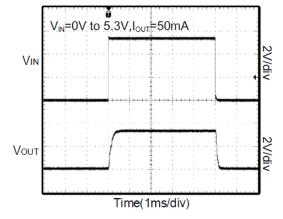


TYPICAL PERFORMANCE CHARACTERISTICS

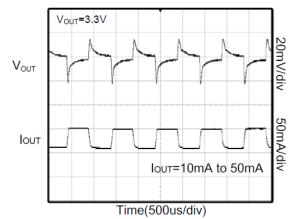
 $V_{IN} = V_{OUT} + 2V$, $C_{IN} = C_{OUT} = 1\mu$ F, $V_{OUT} = 3.3V$, typical values are at $T_A = +25^{\circ}$ C, unless otherwise noted.

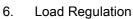


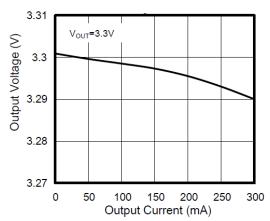
2. Power-Up/Power-Down Output Waveform



4. Load Transient Response

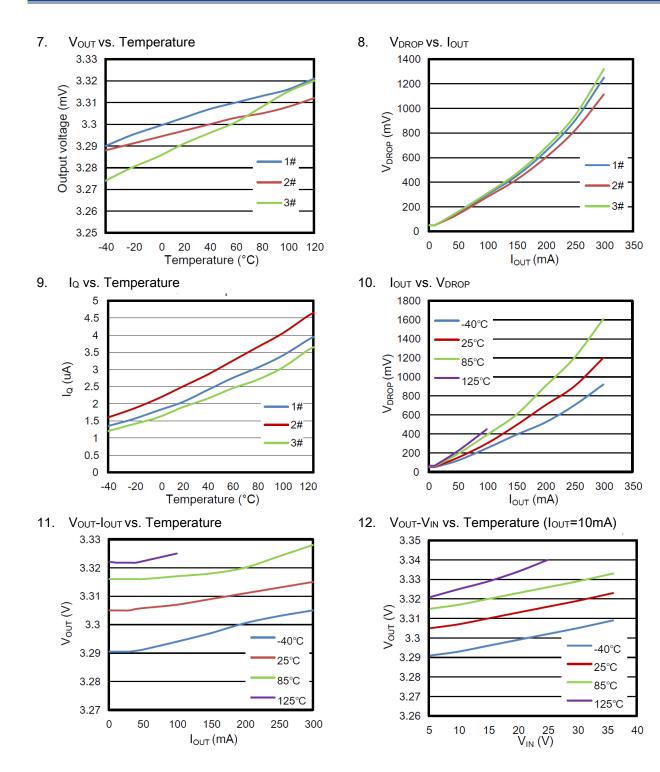






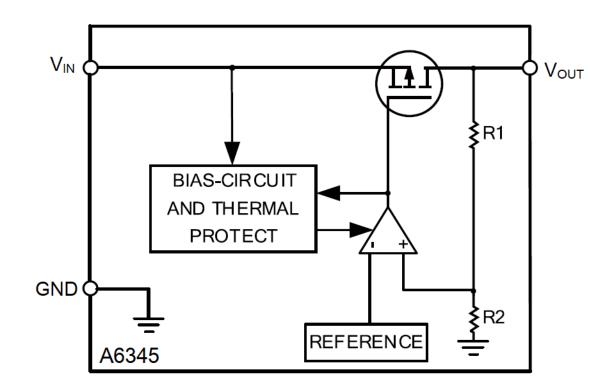


A6345 CMOS LOW DROPOUT VOLTAGE REGULATOR (LDO) 45V, 300mA, LOW QUIESCENT CURRENT





BLOCK DIAGRAM





DETAILED INFORMATION

Overview

The A6345 low-dropout regulators (LDO) consumes only 3µA of quiescent current at light load and delivers excellent line and load transient performance. These characteristics, combined with low noise and good PSRR with low dropout voltage, make this device ideal for portable consumer applications.

Thermal Considerations

When the junction temperature is too high, the thermal protection circuitry sends a signal to the control logic that will shut down the IC. The IC will restart when the temperature has sufficiently cooled down. The maximum power dissipation is dependent on the thermal resistance of the case and the circuit board, the temperature difference between the die junction and the ambient air, and the rate of air flow. The GND pin must be connected to the ground plane for proper dissipation.

Applications Note:

- 1. The phase compensation circuit and ESR of the output capacitor are used inside the circuit to compensate, so a capacitor larger than 1.0uF must be connected to the ground.
- 2. It is recommended to use 1uF polar capacitors for input and output, and to keep the capacitors as close to the V_{IN} and V_{OUT} pins of LDO as possible.
- 3. Pay attention to the use conditions of input and output voltages and load currents to avoid the power consumption (P_D) inside the IC exceeding the maximum power consumption allowed by the package.

 $P_{D}=(V_{IN} - V_{OUT}) \times I_{OUT}$ $T_{PN} = P_{D} \times R_{\theta JA} + T$

T_{PN} is junction temperature

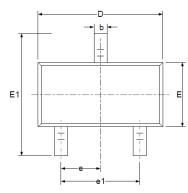
T is ambient temperature。

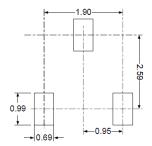
4. When the input voltage V_{IN} is greater than 2.5V, if V_{IN} is also higher than the output set value plus the device dropout voltage, V_{OUT} is equal to the set value. Otherwise, V_{OUT} is equal to V_{IN} minus the dropout voltage. If V_{IN} lower than 2.5V, the V_{OUT} is:



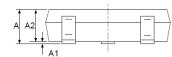
PACKAGE INFORMATION

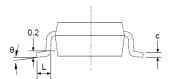
Dimension in SOT-23 (Unit: mm)





RECOMMENDED LAND PATTERN (Unit: mm)

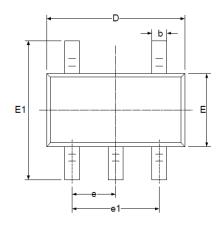


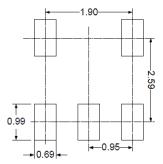


| Symbol | Millimeters | | Inches | | |
|--------|-------------|-------|--------|-------|--|
| | Min | Max | Min | Max | |
| А | 1.050 | 1.250 | 0.041 | 0.049 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| с | 0.100 | 0.200 | 0.004 | 0.008 | |
| D | 2.820 | 3.020 | 0.111 | 0.119 | |
| E | 1.500 | 1.700 | 0.059 | 0.067 | |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 | |
| е | 0.950 | BSC | 0.037 | BSC | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.300 | 0.600 | 0.012 | 0.024 | |
| θ | 0° | 8° | 0° | 8° | |

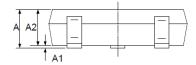


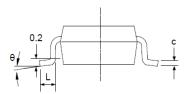
Dimension in SOT-25 (Unit: mm)





RECOMMENDED LAND PATTERN (Unit: mm)

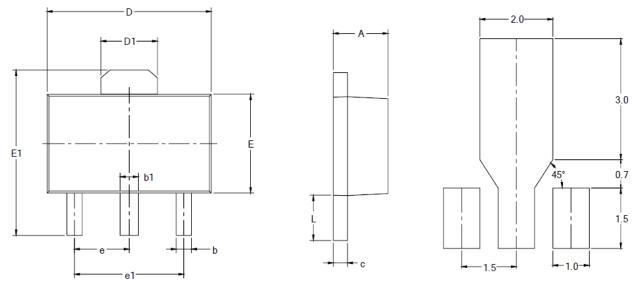




| Symbol | Millimeters | | Inches | | |
|--------|-------------|-------|--------|-------|--|
| | Min | Max | Min | Max | |
| А | 1.050 | 1.250 | 0.041 | 0.049 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| с | 0.100 | 0.200 | 0.004 | 0.008 | |
| D | 2.820 | 3.020 | 0.111 | 0.119 | |
| E | 1.500 | 1.700 | 0.059 | 0.067 | |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 | |
| е | 0.950 | BSC | 0.037 | BSC | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.300 | 0.600 | 0.012 | 0.024 | |
| θ | 0° | 8° | 0° | 8° | |



Dimension in SOT89-3 (Unit: mm)



RECOMMENDED LAND PATTERN (Unit: mm)

| Symbol | Millimeters | | Inches | | |
|--------|-------------|-------|-----------|-------|--|
| | Min | Max | Min | Max | |
| A | 1.400 | 1.600 | 0.055 | 0.063 | |
| b | 0.320 | 0.520 | 0.013 | 0.020 | |
| b1 | 0.400 | 0.580 | 0.016 | 0.023 | |
| с | 0.350 | 0.440 | 0.014 | 0.017 | |
| D | 4.400 | 4.600 | 0.173 | 0.181 | |
| D1 | 1.550 | REF | 0.061 REF | | |
| E | 2.300 | 2.600 | 0.091 | 0.102 | |
| E1 | 3.940 | 4.250 | 0.155 | 0.167 | |
| e | 1.500 BSC | | 0.060 BSC | | |
| e1 | 3.000 BSC | | 0.118 BSC | | |
| L | 0.900 | 1.200 | 0.035 | 0.047 | |



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